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The plateau-insulator transition in the Integer Quantum Hall Effect: When simulation meets experiment

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The transport coefficients for the Hofstadter model of non-interacting electrons in the presence of a magnetic field and strong on-site disorder are computed using an efficient numerical implementation of the non-commutative Kubo formula. The conductivity σ and resistivity ρ tensors are mapped as functions of Fermi energy E_F and temperature T, and an asymptotic analysis in the limit of low temperatures is performed. In particular, the critical behaviors of the model at the plateau-insulator transition is simulated. The results reproduce all the key experimental findings on the plateau-insulator transition in the Integer Quantum Hall Effect: 1) The graphs of ρ_{xx} as function of E_F at different temperatures intersect each other at a single critical point; 2) All these graphs collapse into a single curve after a one-parameter re-scaling; 3) The scaling exponents are in good agreement with the existing theoretical predictions; 4) The flow of σ with the temperature, plotted in the $(\sigma_{xy}, \sigma_{xx})$ plane, obeys the semi-circle law; 5) At the critical point, $\sigma_{xx} = \sigma_{xy} = \frac{1}{2}\frac{e^2}{h}$; 6) The Quantized Hall Insulator phase, characterized by $\sigma_{xx} = \sigma_{xy} = 0$ and $\rho_{xy} = h/e^2$, is observed at low temperatures.

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The plateau-insulator transition (PIT) and the plateau-plateau transitions (PPT) in the Integer Quantum Hall Effect (IQHE) are probably the most studied quantum transitions in condensed matter physics. The critical behavior of the transport coefficients near and at the transition points has been mapped with extraordinary experimental precision, and various aspects were found to be in amazing agreement with the single-parameter scaling theory [1, 2] and the qualitative theory of IQHE [3–5]. However, some aspects remained puzzling, or became puzzling when confronted with new theoretical data, as we shall discuss below. On the theoretical front, to our knowledge, a direct simulation of the experiments was still missing, decades after the first high quality experimental data on PIT and PPT emerged. This is a testament to the extraordinary difficulty of simulating the finite-temperature transport characteristics of disordered systems under magnetic fields. In this Letter, first and foremost, we want to announce that the numerical approach of Ref. [6], based on the non-commutative Kubo formula [7–9], enabled us to accomplish just that, at temperatures low enough to observe and analyze the scaling behavior of the transport coefficients at PIT and PPT (we present results only for PIT). Secondly, we want to announce that the simulations of the PIT with a disordered model of non-interacting electrons reproduces, qualitatively and quantitatively, every aspect of the experimental findings. These are important statements because, firstly, it means we have an effective tool that can be used to explore the remaining puzzling aspect of PI and PP transitions and, secondly, it demonstrates that the Quantized Hall Insulator (QHI) phase [10] exists in models of non-interacting electrons with on-site disorder, contrary to what has been previously assumed.

The Quantum Hall Liquid (QHL) phases corresponding to different plateaus in IQHE and the QHI pase are separated by phase boundaries containing extended quantum states [7]. As such, the PIT and PPT are essentially localization-delocalization transitions. The scaling of the localization length: $\xi \sim (E_F - E_F^c)^{-\nu}$ as E_F approaches the mobility edge E_F^c, combined with the concept of the temperature-induced effective system-size, introduced by Thousless [11], and with the single-parameter scaling hypothesis [1, 2], lead to a temperature-scaling law [12]:

$$\rho(E_F, T) = F((E_F - F_F^c)(T/T_0)^{-\kappa}), \ \kappa = p/2\nu, \tag{1}$$

at the localization-delocalization transition. Here, F is a system dependent function and p is the the dynamical exponent for dissipation. The finite-size scaling exponent ν is expected to be universal (*i*.e. sample and model independent), but the universality at PIT and PPT in IQHE is still debated, especially after the recent contributions that shook the old status quo, as discussed below.

The temperature-scaling of the transport coefficients at PPT was resolved in the early works of Wei *et al* [13–15] and Kawaji and Wakabayashi [16], where the scaling exponent κ appeared to be sample-independent. Subsequent experimental studies [17–23] showed the opposite, but the non-universality of κ was attributed to the different dissipation mechanisms, and later to the nature of disorder [24]. The works by Koch *et al* [25, 26] resolved both κ and ν, and the latter was in good agreement with the existing theoretical predictions at that time ($\nu \approx 2.35$) [27]. Subsequent measurements found similar agreement and by 1997 [28] the idea of universality in IQHE seemed to prevail. Same universality seemed to be at work for PIT [10, 29–33]. The old status quo was again

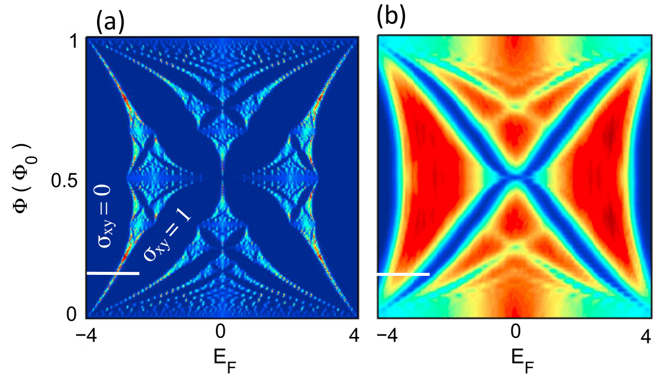

FIG. 1. (Color online) The density of states of the model Eq. 4 as function of the magentic flux Φ (in units of $\Phi_0 = h/e$). The horizontal white line shows the range of energies and the Φ used in our simulations. The QHL phase with $\sigma_{xy} = 1$ and the QHI phase with $\sigma_{xy} = 0$ are marked on the figure. In panel (a), $W = 0$, in which case one can easily recognize the classical Hofstadter butterfly. In panel (b), $W = 3$ and here one can see the impurity states partially or completely filling the spectral gaps visible at $W = 0$.

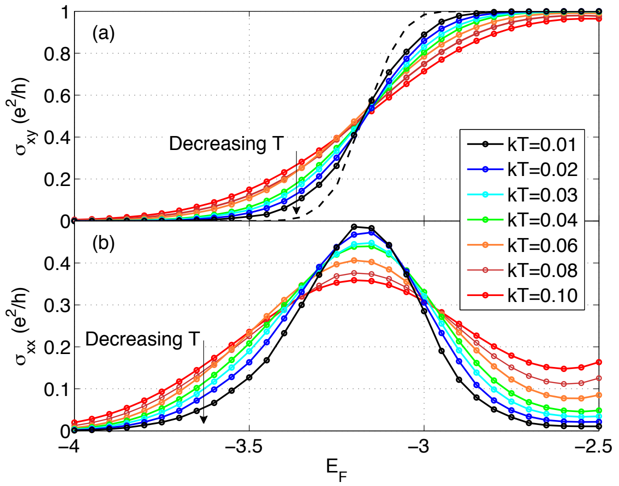

FIG. 2. (Color online) The simulated (a) σ_{xy} and (b) σ_{xx}, as functions of E_F at different temperatures. The dashed line in panel (a) represents σ_{xy} at $T = 0$, computed via the non-commutative Chern number.

reassured by the fine measurements from 2009 [34] performed on alloys with strong and short-range disorder. However, in the same year, a large scale simulation [35] found ν to be about 10% larger than the previously accepted value. As documented in Ref. [36], this value of $\nu \approx 2.6$ has been reproduced (up to small deviations) by several other recent simulations [37–41]. The large discrepancy between the experiment and theory has reignited the debate about the universality in IQHE. To reconcile the experiment and theory, simulations of the experimental conditions are needed, to better understand how accurate is the ”saturation method” used in Ref. [25, 26, 34] to independently measure κ and ν, and to see if this method, in general, underestimates the exponent ν. We hope to convince the reader that this can be solved using the non-commutative Kubo formula.

The second puzzling aspect is that the scaling exponent κ was consistently found to be much larger at PIT ($\kappa \approx 0.58$) than at PPT ($\kappa \approx 0.42$) [31, 33, 42–45]. We should mentioned that κ and ν were never independently measure at PIT, so at this point we do not have a direct confirmation of the universality of ν between PIT and PPT. The different κ values were ascribed to variations in p due to different dissipation mechanisms. Here we report a ν at PIT that is very close to the universally accepted value, so we can confirm this supposition. The third puzzle is the PIT transition into the QHI phase [10, 30, 45–47]. In this phase, even though the direct and Hall conductivities gradually approach zero as $T \to 0$, the Hall resistivity remains quantized at h/e^2. From theoretical point of view, the QHI phase is still a mystery. For example, in the global phase diagram (GPD) of IQHE derived in Ref. [48], the QHL phases are surrounded by an ordinary insulator exhibiting the classical behavior $\rho_{xy} \sim B/nec$ (in agreement with some early experimental reports [49–51]). In spite of several theoretical efforts [32, 52–59], a consistent conclusion has never emerged. Examining the formula: $\rho_{xy} = \sigma_{yx}/(\sigma_{xx}^2 + \sigma_{xy}^2)$, one sees that the quantization of ρ_{xy} is contingent to the peculiar scaling $\sigma_{xy} \sim \sigma_{xx}^2$ as $T \to 0$, which raises the following questions: Is this scaling due to a special form of disorder (like long-range correlated disorder)? Is it due to the electron-electron interaction? We now can settle these questions: Since the QHI phase appears in our model, which includes only on-site disorder and does not include the electron-electron interaction, the answer is “no” to both questions. The observation of the QHI phase in our simulations was possible only because we were able to converge the finite-temperature transport coefficients at temperatures low enough to properly represent the limit $T \to 0$.

Without further ado, we present the details of the simulation and the results. We apply the non-commutative Kubo formula [7–9]:

$$\sigma_{ij}(T,\tau) = -\mathcal{T}\left([x_i, H](1/\tau + \mathcal{L}_H)^{-1}[x_j, \Phi_{FD}(H)]\right), \quad (2)$$

where, $\mathcal{T}$ represents the trace over volume, H is the disordered Hamiltonian, $\boldsymbol{x}$ is the position operator, τ is the relaxation time for dissipation, $\mathcal{L}_H$ is the Liouvillian, and Φ_{FD} is the Fermi-Dirac distribution for a given T and E_F. The non-commutative Kubo formula was the key to the complete theoretical solution of the IQHE [7]. While Eq. 2 makes sense only in the strict thermodynamic limit, we have recently [6] derived a canonical finite-volume (with periodic boundary conditions) approximation $\sigma_{ij}^{(L)}(T,\tau)$, which converges exponentially fast to the thermodynamic limit, as the size L of the sys-

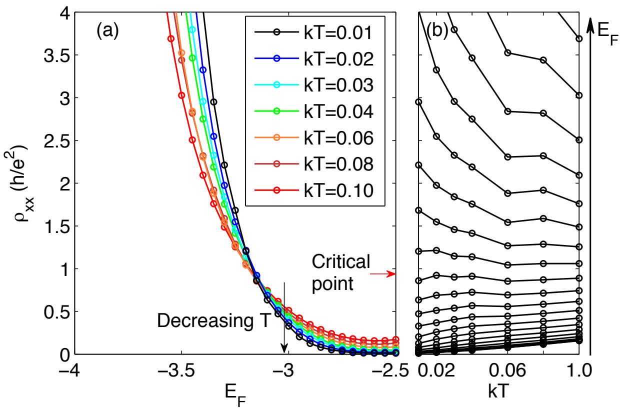

FIG. 3. (Color online) (a) The simulated ρ_{xx} as function of E_F, at different temperatures. (b) ρ_{xx} as function of temperature for various E_F values. The arrow indicates the plateau-insulator transition.

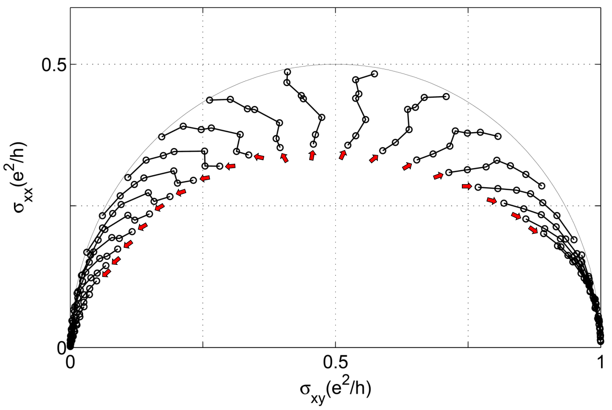

FIG. 4. (Color online) The flow of σ with the temperature. Each flow-line corresponds to a fixed Fermi energy. The temperature decreases in the direction pointed by the arrows. The fine line represents the semi-circle: $\sigma_{xx}^2 + \left(\sigma_{xy} - \frac{1}{2}\frac{e^2}{h}\right)^2 = \left(\frac{1}{2}\frac{e^2}{h}\right)^2$.

tem is increased:

$$|\sigma_{ij}(T,\tau) - \sigma_{ij}^{(L)}(T,\tau)| < const. \times e^{\zeta(T,\tau)L}, \tag{3}$$

The convergence rate $\zeta(T,\tau)$ was found [6] to be directly proportional with T and inverse proportional with τ, a conclusion that holds true regardless of the localized or delocalized nature of the energy spectrum at E_F. In real physical systems, $\tau \sim T^{-p}$, p being the dynamical exponent appearing in Eq. 1. As such, provided the temperature or the system-size are large enough, our algorithm generates well converged results even near and at the critical points. A detailed discussion of the formalism and extensive convergence tests for the present model, at the same temperatures and system-sizes as in the present study, can be found in Ref. [6]. A similar study for Quantum spin-Hall Insulators can be found in Ref. [60].

We use the Hofstadter model [61]:

$$H = -\sum_{\langle n,m\rangle} e^{-i\pi\Phi(\boldsymbol{n}\wedge\boldsymbol{m})} c_{\boldsymbol{n}}^\dagger c_{\boldsymbol{m}} + W \sum_{\boldsymbol{n}} \omega_{\boldsymbol{n}} c_{\boldsymbol{n}}^\dagger c_{\boldsymbol{n}}, \tag{4}$$

in energy units that set the hopping integral to 1. In Eq. 4, Φ is the magnetic flux per unit cell (in units h/e), $\boldsymbol{n} \wedge \boldsymbol{m} = n_1 m_2 - n_2 m_1$, $c_{\mathbf{n}}^\dagger$ creates one electron at site $\boldsymbol{n}$ and $\langle \boldsymbol{n}, \boldsymbol{m}\rangle$ implies nearest neighboring sites. The ω's are independent random variables uniformly distributed in the range $[-1/2, 1/2]$. The simulations are performed on a finite-size 140×140 lattice (hence $L = 140$), with $W = 3$ and $\Phi = 22/L \approx 0.157$. The transport coefficients are self-averaging, hence even a single random configuration can generate converged results if the system-size is large enough [6]. For the lattice-size used in our study, an average over five random configurations led to a root mean square comparable to the markers used in our figures. Fig. 1 summarizes the spectral properties of the model and shows the energy range used in the simulation, chosen to cross from the QHL phase $\sigma_{xy} = 1$ into the QHI phase $\sigma_{xy} = 0$. For clarity, Fig. 1 includes the $W = 0$ case too.

Fig. 2 reports the simulated conductivity tensor as function of Fermi level, at temperatures and dissipations $kT = 1/\tau = 0.01, 0.02, 0.03, 0.04, 0.06$ and 0.08 (k = Boltzmann constant). Note that we are fixing $p = 1$ by making these choices. We have also included a calculation of the non-commutative Chern number (averaged over 30 random configurations), which is equal to σ_{xy} at $T = 0$ [7]. The non-commutative Chern number was computed using the numerical methods detailed in [62, 63]. In panel (a) we see the Hall conductance transitioning from the quantized value of e^2/h to zero, and the transition becoming sharper as $T \to 0$. To a high degree, all the curves in panel (a) intersect each other at one point, the critical point. The slope of the curves at the critical point obey the well known scaling with temperature. Panel (b) reports the direct conductivity. For most of the energy range, σ_{xx} displays an insulating behavior, with σ_{xx} decreasing as $T \to 0$, except for a small region around the critical point where σ_{xx} increases as $T \to 0$, signaling the presence of extended quantum states. The data suggests that this region subsides to the critical point and that the maximum value of σ_{xx} saturates at $\frac{1}{2}\frac{e^2}{h}$ as $T \to 0$, in line with the accepted theoretical picture of PIT [12].

The existence of a single critical point, as opposed to a line of critical points, is best revealed in Fig. 3, which reports $\rho_{xx} = \sigma_{xx}/(\sigma_{xx}^2 + \sigma_{xy}^2)$ as function of E_F (panel a), and as function of kT (panel b). Here, one can see (as expected) $\rho_{xx} \to \infty$ in the QHI side, but $\rho_{xx} \to 0$ in the QHL side. While the latter behavior is usually attributed to a metallic behavior, in the present context it is due to the fact that $\sigma_{xy} \neq 0$ (see the ρ_{xx} formula above). These opposite behaviors of ρ_{xx} on the two sides of PIT are a bonus, because, unlike the σ_{xx} curves, the ρ_{xx} curves intersect

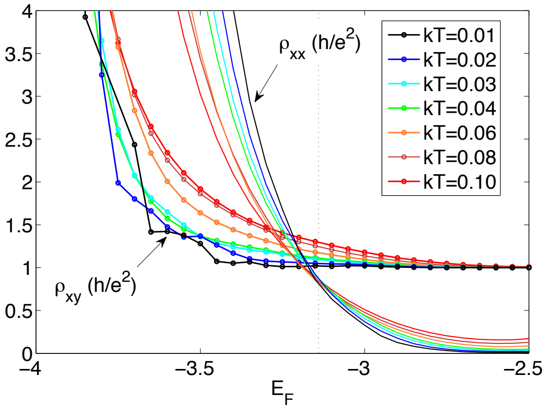

FIG. 5. (Color online) The simulated ρ_{xy} as function of E_F, at different temperatures. The curves at lower temperatures display quantized values well beyond the critical point, which is marked by the vertical dotted line. For convenience we also show the data for ρ_{xx}.

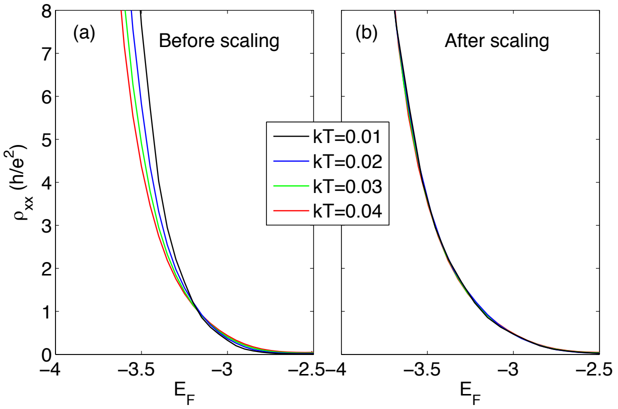

FIG. 6. (Color online) The simulated ρ_{xx} as function of Fermi energy (a) before and (b) after the horizontal axis was rescaled as: $E_F \to E_F^c + (E_F - E_F^c)\left(\frac{T}{T_0}\right)^{\kappa}$, with $E_F^c = -3.15$, $kT_0 = 0.08$ and $\kappa = 0.2$.

each other, very much like σ_{xy} curves do in Fig. 2(a). Furthermore, to a high degree, the curves intersect at a single critical point, exactly as the experimental data showed (see Fig. 1 in Refs. [10], [31] and [33]). The coordinates of the critical point can be extracted with great precision from Fig. 3(b) because, when plotted as function of kT, ρ_{xx} displays distinct behaviors below and above a certain critical Fermi level $E_F^c \approx -3.15$, with the lines curving downwards and upwards, respectively, as $T \to 0$. From the same figure, we see that the critical value ρ_{xx}^c at PIT is virtually equal to h/e^2, and from Fig. 2(a) we estimate σ_{xy}^c to be virtually equal to $\frac{1}{2}\frac{e^2}{h}$, exactly as in experiments [10, 31, 33].

Fig. 4 reports the flow of σ with the temperature, in the $(\sigma_{xy}, \sigma_{xx})$ plane. With a remarkable precision, the flow is seen to approach the semi-circle $\sigma_{xx}^2 + \left(\sigma_{xy} - \frac{1}{2}\frac{e^2}{h}\right)^2 = \left(\frac{1}{2}\frac{e^2}{h}\right)^2$, and then to flow towards either $\sigma_{xy} = 0$ or 1, as $T \to 0$. The semicircle law follows from general theoretical arguments in a "two-phase model" [64] of PIT and PTT. Experiments showed that the law is only approximate at PTT [27] but it is extremely precise at PIT [10]. The reason for the latter is the fact that the semicircle law is equivalent to the quantization of ρ_{xy} at $\frac{h}{e^2}$ at low temperatures (see the expression of ρ_{xy} above).

The semicircle law observed in our simulations already suggests the quantization of ρ_{xy} in our data. And indeed, in Fig. 5, which reports ρ_{xy} as a function of E_F at various temperatures, one can see the ρ_{xy} curves flattening out and converging to the line $\rho_{xy} = \frac{h}{e^2}$ as $T \to 0$, exactly as observed in experiments (see for example Fig. 2 in Ref. [45]). For example, ρ_{xy} at $kT = 0.01$ remains extremely close to this quantized value well beyond E_F^c into the insulating phase. Three simulated quantized values occur when $\sigma_{xy}|_{T=0} = 0.0005$, 0.004, and 0.01, which indicate that the simulation box is much larger than the localization length. This and the semicircle law demonstrate beyond any doubt that, in the Hofstadter model with on-site disorder, the phase on the left side of the PIT is the Quantized Hall Insulator phase observed in Ref. [10].

The last piece of our analysis is the scaling reported in Fig. 6. Here we considered only the lowest four temperatures because the scaling occurs in the asymptotic limit $T \to 0$. As one can see in panel (b), the four ρ_{xx} curves collapse on top of each other after a single-parameter rescaling (see Eq. 1). The best overlap of the rescaled curves was obtained with the scaling exponent $\kappa = 0.2 \pm 0.01$, which compares extremely well with the value $\kappa = 0.192$ obtained from the formula $\kappa = p/2\nu$ with the presently accepted theoretical value $\nu = 2.6$ and $p = 1$ like in our simulations.

In conclusions, the non-commutative Kubo formula enabled us to converge the finite-temperature transport coefficients of the Hofstadter model with on-site disorder, at temperatures low enough to observe the universal critical behavior at the plateau-insulator transition. The simulations reproduced, qualitatively and quantitatively, all the characteristics observed in the experiments on IQHE.

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